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AUTOMOTIVE

RoHS

COMPLIANT HALOGEN

FREE

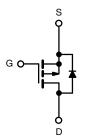
Automotive P-Channel 60 V (D-S) 175 °C MOSFET



PRODUCT SUMMARY					
V _{DS} (V)	-60				
$R_{DS(on)}(\Omega)$ at $V_{GS} = -10 V$	0.0067				
$R_{DS(on)} (\Omega)$ at $V_{GS} = -4.5 \text{ V}$	0.0088				
I _D (A)	-120				
Configuration	Single				
Package	TO-220AB				

FEATURES

- TrenchFET® power MOSFET
- · Package with low thermal resistance
- AEC-Q101 qualified d
- 100 % $\rm R_g$ and UIS tested
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>



P-Channel MOSFET

ABSOLUTE MAXIMUM RATINGS	(T _C = 25 °C, unless	otherwise noted)		
PARAMETER		SYMBOL	LIMIT	UNIT	
Drain-source voltage		V _{DS}	-60	V	
Gate-source voltage		V _{GS}	± 20	V	
Continuous drain current ^a	$T_C = 25 \ ^{\circ}C \ ^{a}$	1-	-120		
	T _C = 125 °C	I _D	-87		
Continuous source current (diode conduction) ^a		I _S	-120	А	
Pulsed drain current ^b		I _{DM}	-480		
Single pulse avalanche current	L = 0.1 mH	I _{AS}	-80		
Single pulse avalanche energy		E _{AS}	320	mJ	
Maximum power dissipation ^b	T _C = 25 °C	D-	300	W	
	T _C = 125 °C	PD	100	vv	
Operating junction and storage temperature ra	inge	T _J , T _{stg}	-55 to +175	°C	

THERMAL RESISTANCE RATINGS				
PARAMETER		SYMBOL	LIMIT	UNIT
Junction-to-ambient	PCB mount ^c	R _{thJA}	40	°C/W
Junction-to-case (drain)		R _{thJC}	0.5	0/10

Notes

- a. Package limited.
- b. Pulse test; pulse width $\leq 300~\mu\text{s},~\text{duty}~\text{cycle} \leq 2~\%$
- c. When mounted on 1" square PCB (FR4 material)

d. Parametric verification ongoing

SQP120P06-6m7L



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SPECIFICATIONS ($T_C = 25 \ ^{\circ}C$,	unless otherw	vise noted)						
PARAMETER	SYMBOL	TEST CONDITIONS		MIN.	TYP.	MAX.	UNIT	
Static							•	
Drain-source breakdown voltage	V _{DS}	V _{GS}	= 0, I _D = -250 μA	-60	-	-	v	
Gate-source threshold voltage	V _{GS(th)}	V _{DS} =	V_{GS} , I_D = -250 μ A	-1.5	-2.0	-2.5	v	
Gate-source leakage	I _{GSS}	V _{DS} =	0 V, V_{GS} = ± 20 V	-	-	± 100	nA	
		$V_{GS} = 0 V$	V _{DS} = -60 V	I	-	-1		
Zero gate voltage drain current	I _{DSS}	$V_{GS} = 0 V$	V_{DS} = -60 V, T_{J} = 125 °C	I	-	-50	μA	
		$V_{GS} = 0 V$	V_{DS} = -60 V, T _J = 175 °C	I	-	-250		
On-state drain current ^a	I _{D(on)}	$V_{GS} = -10 V$	$V_{DS} \le -5 V$	-120	-	-	Α	
		$V_{GS} = -10 V$	I _D = -30 A	I	0.0056	0.0067	Ω	
Drain-source on-state resistance ^a	P	$V_{GS} = -10 V$	$I_D = -30 \text{ A}, \text{ T}_J = 125 ^\circ\text{C}$	I	-	0.0110		
	R _{DS(on)}	$V_{GS} = -10 V$	I _D = -30 A, T _J = 175 °C	-	-	0.0130		
		$V_{GS} = -4.5 V$	I _D = -20 A	-	0.0070	0.0088		
Forward transconductance ^b	9 _{fs}	V _{DS} =	= -15 V, I _D = -30 A	-	90	-	S	
Dynamic ^b								
Input capacitance	C _{iss}			I	11 423	14 280		
Output capacitance	Coss	$V_{GS} = 0 V$	V_{DS} = -25 V, f = 1 MHz	I	1034	1295	pF	
Reverse transfer capacitance	C _{rss}			-	809	1015		
Total gate charge ^c	Qg			I	180	270		
Gate-source charge ^c	Q _{gs}	V_{GS} = -10 V	V_{DS} = -30 V, I_{D} = -110 A	I	31	-	nC	
Gate-drain charge ^c	Q _{gd}			-	43	-		
Gate resistance	Rg		f = 1 MHz	1.1	2.27	3.5	Ω	
Turn-on delay time ^c	t _{d(on)}			-	15	23		
Rise time ^c	tr	V_{DD} = -30 V, R _L = 0.27 Ω I _D \cong -110 A, V _{GEN} = -10 V, R _g = 1 Ω		-	23	35	ns	
Turn-off delay time ^c	t _{d(off)}			-	97	146		
Fall time ^c	t _f			-	32	48		
Source-Drain Diode Ratings and Char	acteristics ^b							
Pulsed current ^a	I _{SM}			-	-	-480	А	
Forward voltage	V _{SD}	I _F = ·	-100 A, V _{GS} = 0 V	-	-0.95	-1.5	V	

Notes

a. Pulse test; pulse width \leq 300 µs, duty cycle \leq 2 %

b. Guaranteed by design, not subject to production testing

c. Independent of operating temperature

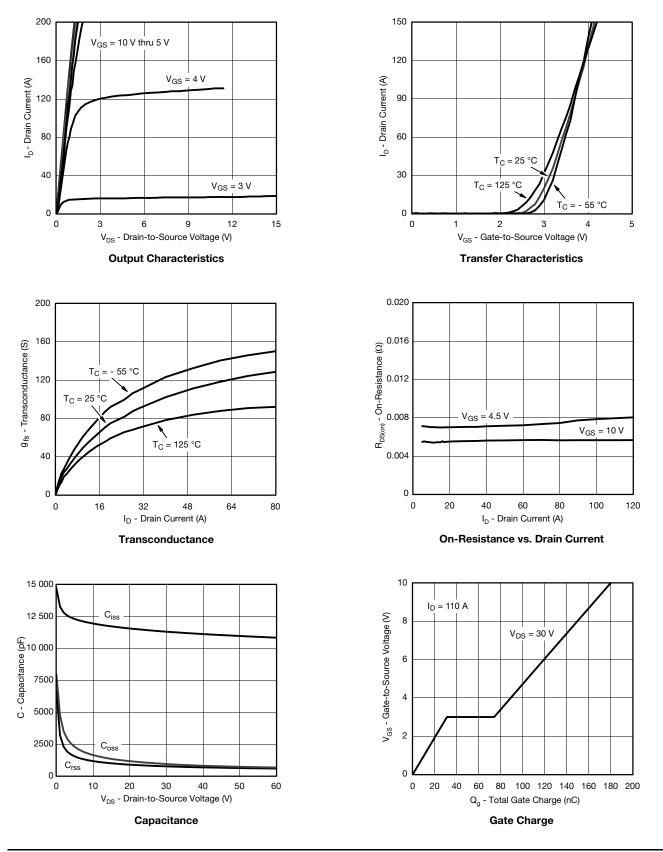
Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

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TYPICAL CHARACTERISTICS ($T_A = 25 \text{ °C}$, unless otherwise noted)



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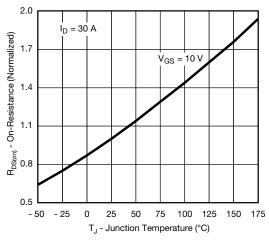
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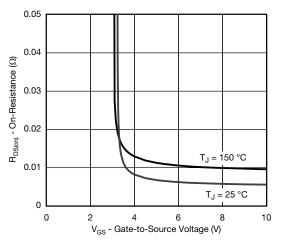
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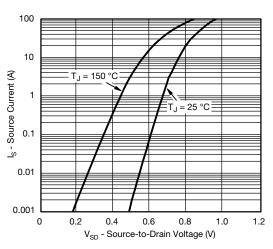
TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise noted)



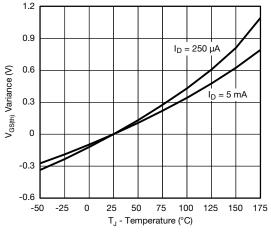
On-Resistance vs. Junction Temperature



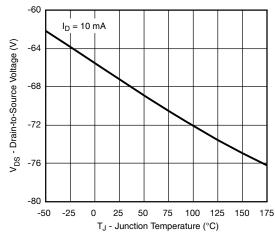
On-Resistance vs. Gate-to-Source Voltage



Source Drain Diode Forward Voltage



Threshold Voltage



Drain Source Breakdown vs. Junction Temperature

4

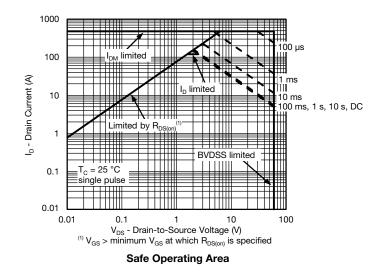
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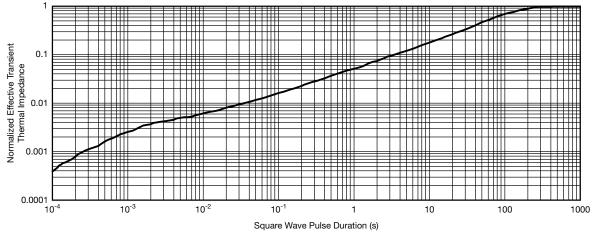


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THERMAL RATINGS ($T_A = 25 \text{ °C}$, unless otherwise noted)





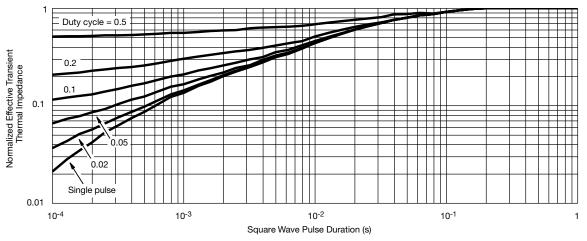
Normalized Thermal Transient Impedance, Junction-to-Ambient



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THERMAL RATINGS (T_A = 25 °C, unless otherwise noted)



Normalized Thermal Transient Impedance, Junction-to-Case

Note

• The characteristics shown in the two graphs

S18-0554-Rev. A, 04-Jun-2018

- Normalized Transient Thermal Impedance Junction-to-Ambient (25 °C)

- Normalized Transient Thermal Impedance Junction-to-Case (25 °C)

are given for general guidelines only to enable the user to get a "ball park" indication of part capabilities. The data are extracted from single pulse transient thermal impedance characteristics which are developed from empirical measurements. The latter is valid for the part mounted on printed circuit board - FR4, size 1" x 1" x 0.062", double sided with 2 oz. copper, 100 % on both sides. The part capabilities can widely vary depending on actual application parameters and operating conditions

Vishay Siliconix maintains worldwide manufacturing capability. Products may be manufactured at one of several qualified locations. Reliability data for Silicon Technology and Package Reliability represent a composite of all qualified locations. For related documents such as package / tape drawings, part marking, and reliability data, see www.vishay.com/ppg?77806.

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TO-220AB



	MILLIMETERS		INC	HES
DIM.	MIN.	MAX.	MIN.	MAX.
А	4.25	4.65	0.167	0.183
b	0.69	1.01	0.027	0.040
b(1)	1.20	1.73	0.047	0.068
С	0.36	0.61	0.014	0.024
D	14.85	15.49	0.585	0.610
D2	12.19	12.70	0.480	0.500
E	10.04	10.51	0.395	0.414
е	2.41	2.67	0.095	0.105
e(1)	4.88	5.28	0.192	0.208
F	1.14	1.40	0.045	0.055
H(1)	6.09	6.48	0.240	0.255
J(1)	2.41	2.92	0.095	0.115
L	13.35	14.02	0.526	0.552
L(1)	3.32	3.82	0.131	0.150
ØР	3.54	3.94	0.139	0.155
Q	2.60	3.00	0.102	0.118
	0413-Rev. P,		0.102	0.118

Note

 * M = 1.32 mm to 1.62 mm (dimension including protrusion) Heatsink hole for HVM



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